LM387/LM387A Low Noise Dual Preamplifier

The LM387 is a dual preamplifier for the amplification of low level signals in applications requiring optimum noise performance. Each of the two amplifiers is completely independent, with an internal power supply decoupler-regulator, providing 110 dB supply rejection and 60 dB channel separation. Other outstanding features include high gain (104 dB), large output voltage swing (V $_{\rm CC}$ - 2V)p-p, and wide power bandwidth (75 kHz, 20 Vp-p). The LM387A is a selected version of the LM387 that has lower noise in a NAB tape circuit, and can operate on a larger supply voltage. The LM387 operates from a single supply across the wide range of 9V to 30V, the LM387A operates on a supply of 9V to

The amplifiers are internally compensated for gains greater than 10. The LN387, LM387A is available in an 8-lead dualin-line package. The LM387, LM387A is biased like the LM381. See AN-64 and AN-104.

Features

1.0 μV total input noise ■ Low noise

■ High gain 104 dB open loop

■ Single supply operation

9 to 30V ■ Wide supply range LM387 9 to 40V I M387A

Power supply rejection

Large output voltage swing (V_{CC} - 2V)p-p

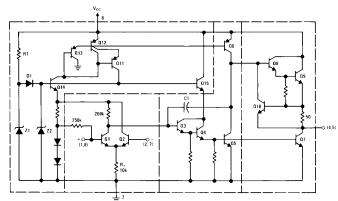
■ Wide bandwidth 15 MHz unity gain

■ Power bandwidth 75 kHz, 20 Vp-p

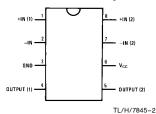
■ Internally compensated

■ Short circuit protected ■ Performance similar to LM381

Schematic and Connection Diagrams



Dual-In-Line Package



Top View

Order Number LM387N or LM387AN See NS Package Number N08E

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Typical Applications

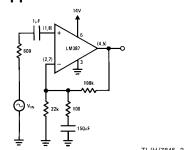


FIGURE 1. Flat Gain Circuit (A_V = 1000)

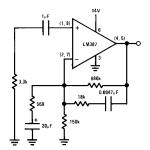


FIGURE 2. NAB Tape Circuit

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110 dB

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage

LM387 LM387A Power Dissipation (Note 1)
Operating Temperature Range
Storage Temperature Range

 $\begin{array}{c} \text{1.5W} \\ \text{0°C to } + \text{70°C} \\ -65\text{°C to } + \text{150°C} \end{array}$

Lead Temperature (Soldering, 10 sec.) 260°C

Electrical Characteristics $T_A = 25^{\circ}C$, $V_{CC} = 14V$, unless otherwise stated

+30V

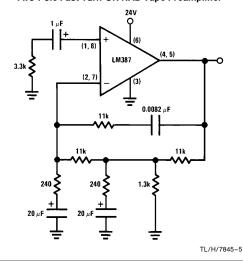
+40V

Parameter	Conditions	Min	Тур	Max	Units
Voltage Gain	Open Loop, f = 100 Hz		160,000		V/V
Supply Current	LM387, V_{CC} 9V-30V, $R_L = \infty$ LM387A, V_{CC} 9V-40V, $R_L = \infty$		10 10		mA mA
Input Resistance Positive Input Negative Input		50	100 200		kΩ kΩ
Input Current Negative Input			0.5	3.1	μΑ
Output Resistance	Open Loop		150		Ω
Output Current	Source Sink		8 2		mA mA
Output Voltage Swing	Peak-to-Peak		V _{CC} -2		V
Unity Gain Bandwidth			15		MHz
Large Signal Frequency Response	20 Vp-p (V $_{CC}$ $>$ 24V), THD \leq 1%		75		kHz
Maximum Input Voltage	Linear Operation			300	mVrm
Supply Rejection Ratio Input Referred	f = 1 kHz		110		dB
Channel Separation	f = 1 kHz	40	60		dB
Total Harmonic Distortion	60 dB Gain, f = 1 kHz		0.1	0.5	%
Total Equivalent Input Noise (Flat Gain Cricuit)	10 Hz-10,000 Hz LM387 <i>Figure 1</i>		1.0	1.2	μVrm
Output Noise NAB Tape Playback Circuit Gain of 37 dB	Unweighted LM387A Figure 2		400	700	μVrm:

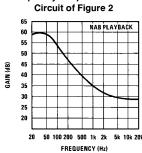
Note 1: For operation in ambient temperatures above 25°C, the device must be derated based on a 150°C maximum junction temperature and a thermal resistance of 80°C/W junction to ambient.

Typical Applications (Continued)

Two-Pole Fast Turn-ON NAB Tape Preamplifier



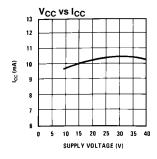
Frequency Response of NAB

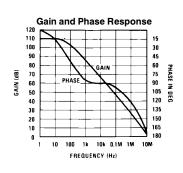


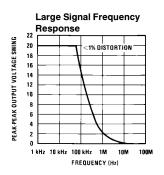
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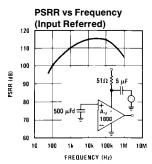
2

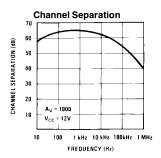


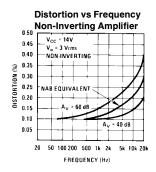


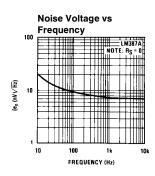


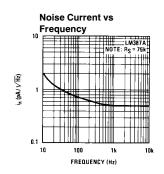


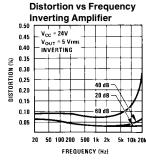








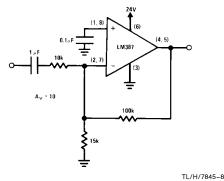




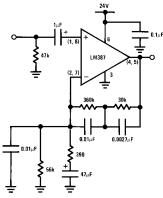
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Typical Applications (Continued)

Inverting Amplifier Ultra-Low Distortion

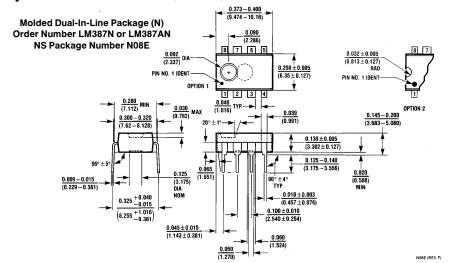


Typical Magnetic Phono Preamplifier



TL/H/7845-9

Physical Dimensions inches (millimeters)



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